

## **HSD119**

# Silicon Epitaxial Planar Diode for High Speed Switching

REJ03G1309-0100 Rev.1.00 Oct 27, 2005

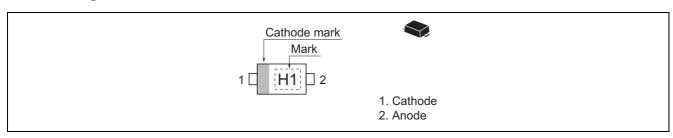
#### **Features**

- Low capacitance. (C = 2.0 pF max)
- Short reverse recovery time.  $(t_{rr} = 3.0 \text{ ns max})$
- Super small Flat Lead Package (SFP) is suitable for surface mount design.

### Ordering Information

Type No.	Laser Mark	Package Name	Package Code (Previous Code)
HSD119	H1	SFP	PUSF0002ZB-A (SFP)

### **Pin Arrangement**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Value	Unit
Peak reverse voltage	$V_{RM}$	85	V
Reverse voltage	$V_R$	80	V
Average rectified current	Io	100	mA
Peak forward current	I <sub>FM</sub>	300	mA
Non-Repetitive peak forward surge current	I <sub>FSM</sub> *	4	А
Junction temperature	Tj	125	°C
Storage temperature	Tstg	-55 to +125	°C

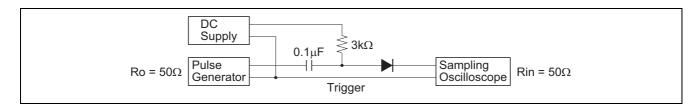
Note: Within 1µs forward surge current.

### **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Forward voltage	$V_{F1}$	_	_	0.8	V	I <sub>F</sub> = 10 mA
	$V_{F2}$	_	_	1.2		I <sub>F</sub> = 100 mA
Reverse current	I <sub>R</sub>	_	_	0.1	μΑ	V <sub>R</sub> = 80 V
Capacitance	С	_	_	2.0	pF	V <sub>R</sub> = 0 V, f = 1 MHz
Reverse recovery time*1	t <sub>rr</sub>	_	_	3.0	ns	$I_F = 10 \text{ mA}, V_R = 6 \text{ V}, R_L = 50 \Omega$

Note: 1. Reverse recovery time test circuit



### **Main Characteristics**

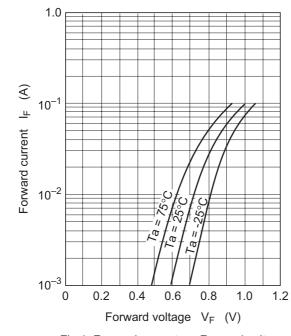


Fig.1 Forward current vs. Forward voltage

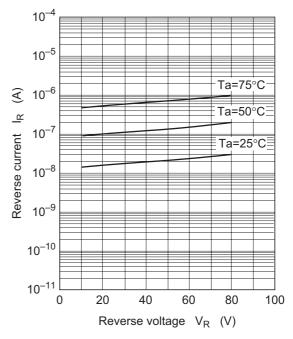
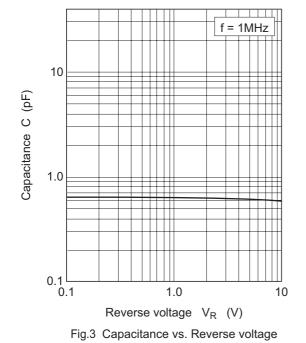
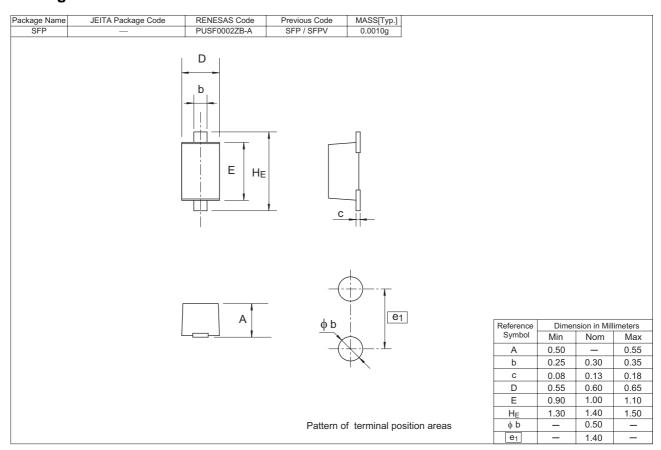


Fig.2 Reverse current vs. Reverse voltage



### **Package Dimensions**



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